

# isc N-Channel MOSFET Transistor

### AOTF7N70

### FEATURES

- Drain Current –I\_D= 7A@ T\_C=25 $^\circ\!\!\mathbb{C}$
- Drain Source Voltage-: V<sub>DSS</sub>= 700V(Min)
- Static Drain-Source On-Resistance
- : R<sub>DS(on)</sub> = 1.8 Ω (Max)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### DESCRIPTION

• Designed for use in switch mode power supplies and general purpose applications.

SYMBOL	PARAMETER	VALUE	UNIT				
V <sub>DSS</sub>	Drain-Source Voltage	700	v				
V <sub>GS</sub>	Gate-Source Voltage-Continuous	±30	V				
ID	Drain Current-Continuous 7		A				
I <sub>DM</sub>	Drain Current-Single Pluse	24	A				
P <sub>D</sub>	Total Dissipation @T <sub>c</sub> =25℃	38.5	w				
TJ	Max. Operating Junction Temperature	-55~150	°C				
T <sub>stg</sub>	Storage Temperature	-55~150	°C				

PARAMETER

Thermal Resistance, Junction to Case

### ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

**THERMAL CHARACTERISTICS** 

SYMBOL

Rth j-c

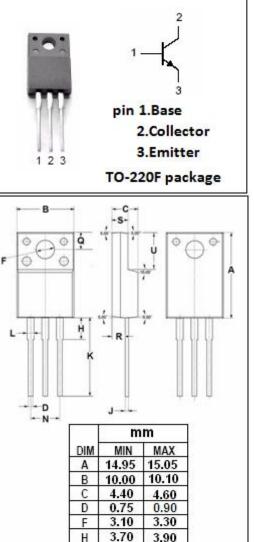
### *isc website:* <u>www.iscsemi.com</u> <sup>1</sup> *isc & iscsemi* is registered trademark

UNIT

°C/W

MAX

3.25



0.50

13.4

1.10

5.00

2.70

2.20

2.65

6.40

J

N

0

R

s

U

0.70

13.6

1.30

5.20

2.90

2.40

6.60

2.90



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### **ELECTRICAL CHARACTERISTICS**

#### T<sub>c</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮРЕ	МАХ	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> = 0.25mA	700			v
$V_{GS(th)}$	Gate Threshold Voltage	V <sub>DS</sub> = 5V; I <sub>D</sub> = 0.25mA	3		4.5	V
$R_{\text{DS(on)}}$	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> = 3.5A			1.8	Ω
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> = ±30V;V <sub>DS</sub> = 0			±100	nA
IDSS	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 700V; V <sub>GS</sub> = 0 V <sub>DS</sub> = 560V; V <sub>GS</sub> = 0@T <sub>J</sub> = 55℃			1 10	μA
$V_{SD}$	Forward On-Voltage	I <sub>S</sub> = 1A; V <sub>GS</sub> = 0			1	v



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